



LITE-ON TECHNOLOGY CORPORATION

Property of Lite-On Only

ABSOLUTE MAXIMUM RATINGS AT TA=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation	150	mW
Peak Forward Current (300pps, 10 μs pulse)	2	A
Continuous Forward Current	100	mA
Reverse Voltage	5	V
Operating Temperature Range	-40°C to + 85°C	
Storage Temperature Range	-55°C to + 100°C	
Lead Soldering Temperature [1.6mm(.063") From Body]	260°C for 5 Seconds	

ELECTRICAL OPTICAL CHARACTERISTICS AT TA=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	BIN NO.
Aperture Radiant Incidence	E _e	0.44		0.96	mW/cm ²	I _F = 20mA	BIN A
		0.64		1.20			BIN B
		0.80		1.68			BIN C
		1.12					BIN D
Radiant Intensity	I _E	3.31		7.22	mW/sr	I _F = 20mA	BIN A
		4.81		9.02			BIN B
		6.02		12.63			BIN C
		8.42					BIN D
Peak Emission Wavelength	λ _{Peak}		940		nm	I _F = 20mA	
Spectral Line Half-Width	Δλ		50		nm	I _F = 20mA	
Forward Voltage	V _F		1.2	1.6	V	I _F = 20mA	
Reverse Current	I _R			100	μA	V _R = 5V	
Viewing Angle (See FIG.6)	2θ _{1/2}		40		deg.		

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTICS CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

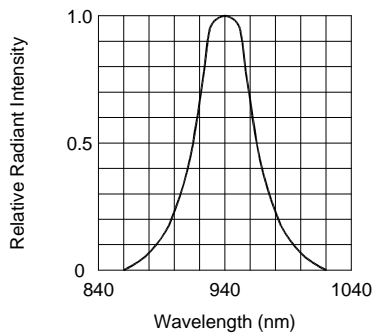


FIG.1 SPECTRAL DISTRIBUTION

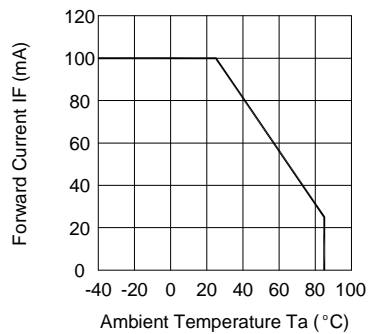


FIG.2 FORWARD CURRENT VS. AMBIENT TEMPERATURE

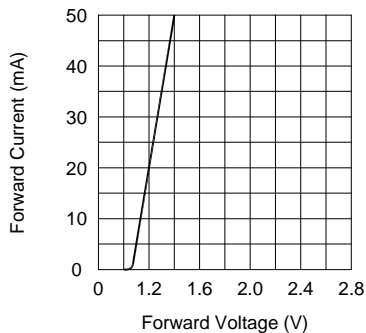


FIG.3 FORWARD CURRENT VS. FORWARD VOLTAGE

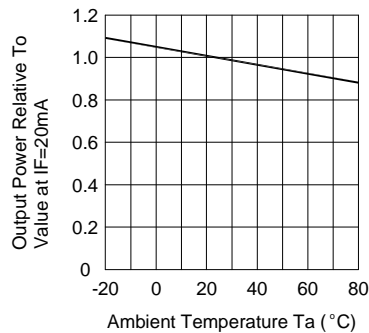


FIG.4 RELATIVE RADIANT INTENSITY VS. AMBIENT TEMPERATURE

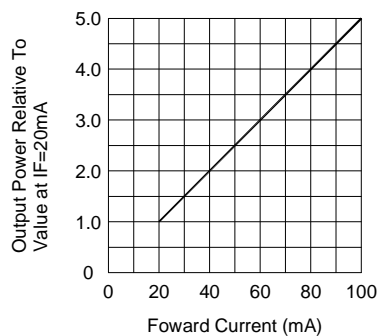


FIG.5 RELATIVE RADIANT INTENSITY VS. FORWARD CURRENT

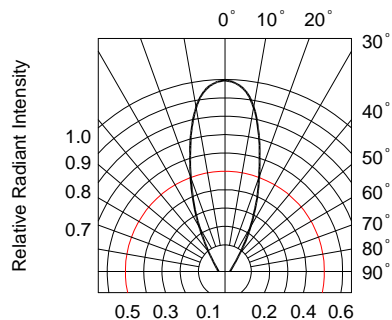


FIG.6 RADIATION DIAGRAM